

10MHz, RRIO, CMOS Operational Amplifier for Cost-Sensitive Systems

General Description

ET85601 is a signal low-voltage (1.8V to 5.5V) operational amplifier (op amp) with rail-to-rail input- and output- swing capabilities. The device is highly cost-effective solutions for applications where low-voltage operation, a small footprint, and high capacitive load drive are required. Although the capacitive load drive of the ET85601 is 100pF, the resistive open-loop output impedance makes stabilizing with higher capacitive loads simpler. The op amp is designed specifically for low-voltage operation (1.8V to 5.5V).

ET85601 is specified for the extended industrial/automotive temperature range (-40°C to +125°C). It is available in SOT23-5 / SC70-5 packages.

Features

- Rail-to-rail input and output
- Low input offset voltage: ± 0.3 mV
- Unity-gain bandwidth: 10 MHz
- Low broadband noise: $10 \text{ nV}/\sqrt{\text{Hz}}$
- Low input bias current: ± 1 pA
- Low quiescent current: 550 μA
- Unity-gain stable
- Internal RFI and EMI filter
- Operational supply voltage range 1.8 V to 5.5V
- Easier to stabilize with higher capacitive load due to resistive open-loop output impedance
- Extended temperature range: -40°C to 125°C

Applications

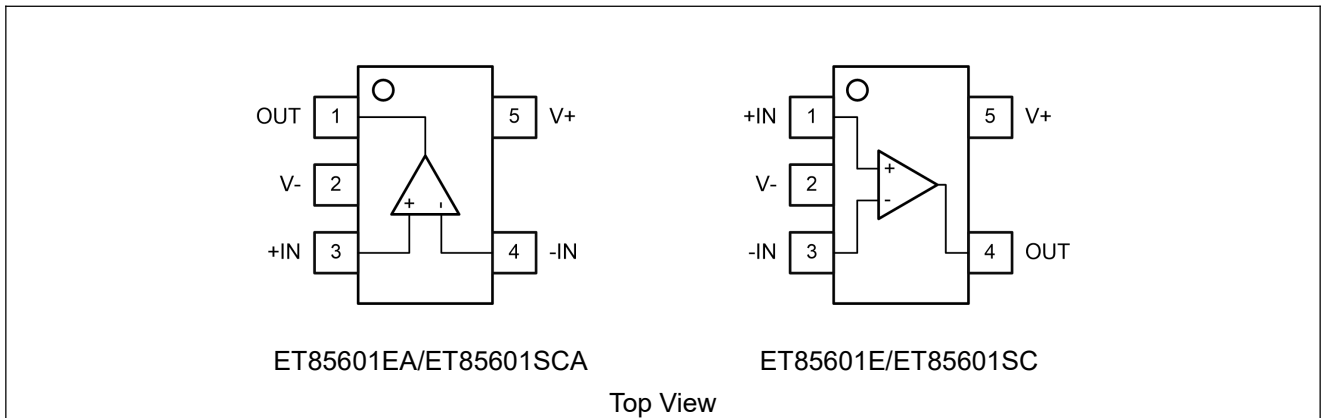
- Temperature sensors
- Smoke detectors
- Wearable devices
- Laptop computers
- Sensor signal conditioning
- Power modules
- Active filters
- Low-side current sensing

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Device information

Part No.	Package	MSL
ET85601E / ET85601EA	SOT23-5	3
ET85601SC / ET85601SCA	SC70-5	1

Pin Configuration



Pin Function

Pin Number		Symbol	Descriptions
ET85601E/SC	ET85601EA/SCA		
4	1	OUT	Output
2	2	V-	Negative supply
1	3	+IN	Non-inverting input
3	4	-IN	Inverting input
5	5	V+	Positive supply

Functional Description

Operating Voltage

ET85601 operates from 1.8 V to 5.5 V, is unity-gain stable, and is designed for a wide range of general-purpose applications.

Rail-to-Rail Input

The input common-mode voltage range extends 100 mV beyond the supply rails for the full supply voltage range of 1.8 V to 5.5 V. This performance is achieved with a complementary input stage.

Rail-to-Rail Output

Designed as a low-power, low-voltage operational amplifier, the ET85601 delivers a robust output drive capability. A class AB output stage with common-source transistors achieves full rail-to-rail output swing capability. For resistive loads of 10 k Ω , the output swings to within 15 mV of either supply rail, regardless of the applied power-supply voltage. Different load conditions change the ability of the amplifier to swing close to the rails.

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Absolute Maximum Ratings

Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are only stress ratings, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions are not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Symbol	Parameter	Value	Unit
V _S	Supply Voltage:(V+) - (V-)	0 to 6	V
V _{IC}	Common-mode Input Voltage ⁽¹⁾	(V-)-0.5 to (V+)+0.5	V
V _{ID}	Differential Input Voltage ⁽¹⁾	(V+) - (V-)+0.2	V
I _{IN}	Signal input terminals Current ⁽¹⁾	-10 to +10	mA
I _{SC}	Output short-circuit current ⁽²⁾	Continuous	
V _{ESD}	ESD (Human Body Model)	±2500	V
	ESD (Component Discharge Model)	±1000	V
T _{STG}	Storage Temperature Range	-65 to +150	°C
T _{J(MAX)}	Max Junction Temperature Range	+150	°C

Note1:Input pins are diode-clamped to the power-supply rails. Current limit input signals that can swing more than 0.5 V beyond the supply rails to 10 mA or less.

Note2:Short-circuit to ground, one amplifier per package.

Thermal Characteristics

Symbol	Package	Ratings	Value	Unit
R _{θJA}	SOT23-5	Thermal Characteristics, Thermal Resistance, Junction-to-Air	215	°C/W
	SC70-5		230	°C/W

Recommended Operating Conditions

Symbol	Parameter	Value	Unit
V _S	Supply Voltage: (V+) - (V-)	1.8(±0.9) ~ 5.5(±2.75)	V
T _A	Operating Temperature Range	-40 ~ +125	°C

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Electrical Characteristics

$V_S = (V+) - (V-) = 1.8\text{V to } 5.5\text{V}$ ($\pm 0.9\text{V to } \pm 2.75\text{V}$), $T_A = 25^\circ\text{C}$, $R_L = 10\text{k}\Omega$ connected to $V_S/2$, and $V_{CM} = V_{OUT} = V_S/2$ (unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
OFFSET VOLTAGE						
V _{OS}	Input offset voltage	V _S = 5 V		±0.3	±2	mV
		V _S = 5 V, T _A = -40°C to 125°C			±2.5	
dV _{OS} /dT	V _{OS} vs temperature	V _S = 5 V, T _A = -40°C to 125°C		±0.53		µV/°C
PSRR	Power-supply rejection ratio	V _S = 1.8 to 5.5 V, V _{CM} = (V-)		±7	±80	µV/V
INPUT VOLTAGE RANGE						
V _{CM}	Common-mode voltage range	V _S = 1.8 V to 5.5 V	(V-)-0.1		(V+)+0.1	V
CMRR	Common-mode rejection ratio	V _S = 5.5 V, (V-) - 0.1 V < V _{CM} < (V+) - 1.4 V, T _A = -40°C to 125°C	70	103		dB
		V _S = 5.5 V, V _{CM} = -0.1 V to 5.6 V, T _A = -40°C to 125°C	57	87		
		V _S = 1.8 V, (V-) - 0.1 V < V _{CM} < (V+) - 1.4 V, T _A = -40°C to 125°C		88		
		V _S = 1.8 V, V _{CM} = -0.1 V to 1.9 V, T _A = -40°C to 125°C		81		
INPUT BIAS CURRENT						
I _B	Input bias current	V _S = 5 V		±1		pA
I _{OS}	Input offset current			±1		pA
NOISE						
E _n	Input voltage noise (peak to peak)	f = 0.1 Hz to 10 Hz, V _S = 5 V		4.77		µV _{PP}
e _n	Input voltage noise density	f = 1 kHz, V _S = 5 V		16		nV/√Hz
		f = 10 kHz, V _S = 5 V		10		
i _n	Input current noise density ⁽³⁾	f = 1 kHz, V _S = 5 V		23		fA/√Hz
INPUT CAPACITANCE						
C _{ID}	Differential ⁽³⁾			2		pF
C _{IC}	Common-mode ⁽³⁾			4		pF

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Electrical Characteristics (Continued)

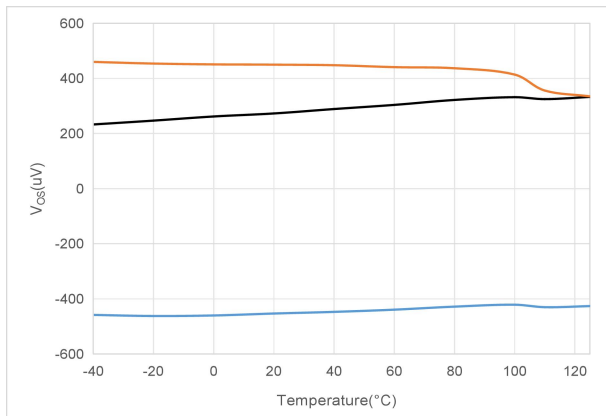
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
OPEN-LOOP GAIN						
A _{OL}	Open-loop voltage gain	V _S = 1.8 V, R _L = 10 kΩ (V-) + 0.04 V < V _O < (V+) - 0.04 V		100		dB
		V _S = 5.5 V, R _L = 10 kΩ (V-) + 0.1 V < V _O < (V+) - 0.1 V	104	130		
		V _S = 1.8 V, R _L = 2 kΩ (V-) + 0.06 V < V _O < (V+) - 0.06 V		100		
		V _S = 5.5 V, R _L = 2 kΩ (V-) + 0.15 V < V _O < (V+) – 0.15 V		130		
FREQUENCY RESPONSE						
GBW	Gain-bandwidth product	V _S = 5 V, G = +1		10		MHz
φ _m	Phase margin	V _S = 5 V, G = +1		55		°
SR	Slew rate	V _S = 5 V, G = +1		6		V/μs
t _s	Settling time ⁽³⁾	To 0.1%, V _S = 5 V, 2V step, G = +1, C _L = 100 pF		0.5		μs
		To 0.01%, V _S = 5 V, 2V step, G = +1, C _L = 100 pF		1		
t _{OR}	Overload recovery time	V _S = 5 V, V _{IN} × gain > V _S		0.2		μs
THD+N	Total harmonic distortion + noise	V _S = 5.5 V, V _{CM} = 2.5 V, V _O = 1 V _{RMS} , G = +1, f = 1 kHz,		0.0008		%
OUTPUT						
V _O	Voltage output swing from supply rails	V _S = 5.5 V, R _L = 10 kΩ			20	mV
		V _S = 5.5 V, R _L = 2 kΩ			60	
I _{SC}	Short-circuit current	V _S = 5 V		±50		mA
Z _O	Open-loop output impedance ⁽³⁾	V _S = 5 V, f = 10MHz		100		Ω
POWER SUPPLY						
V _S	Specified voltage range		1.8 (±0.9)		5.5 (±2.75)	V
I _Q	Quiescent current per amplifier	I _O = 0 mA, V _S = 5.5 V		550	750	μA
		I _O = 0 mA, V _S = 5.5 V, T _A = -40°C to 125°C			800	

Note3 : Guaranteed by design.

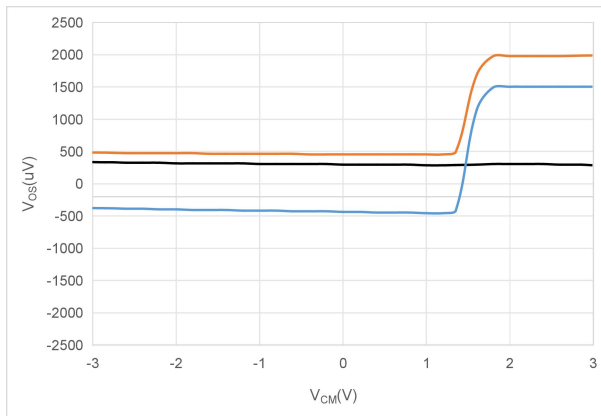
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Typical Characteristics

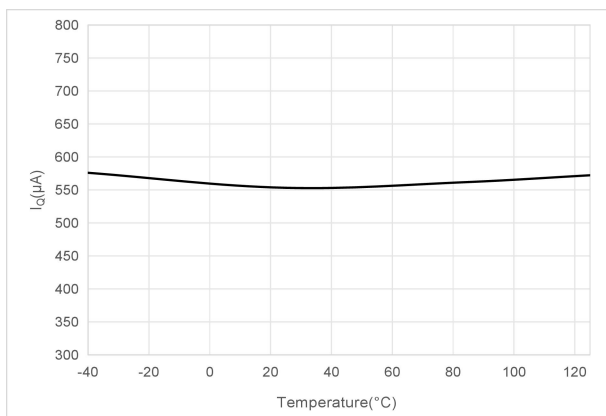
$V_S = 5.5\text{ V}(\pm 2.75\text{ V})$, $V_{CM} = V_{OUT} = V_S/2$, and $R_L = 10\text{ k}\Omega$ connected to $V_S/2$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)



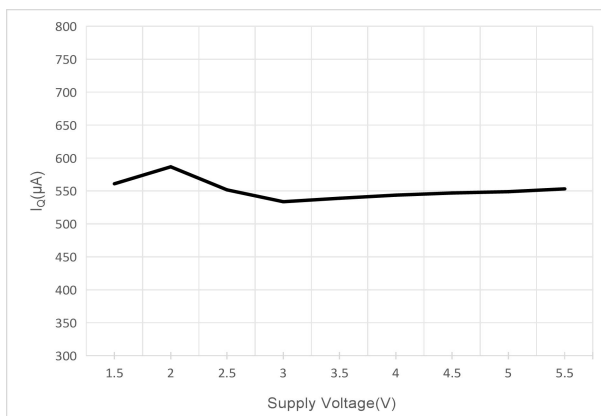
Offset Voltage vs Temperature



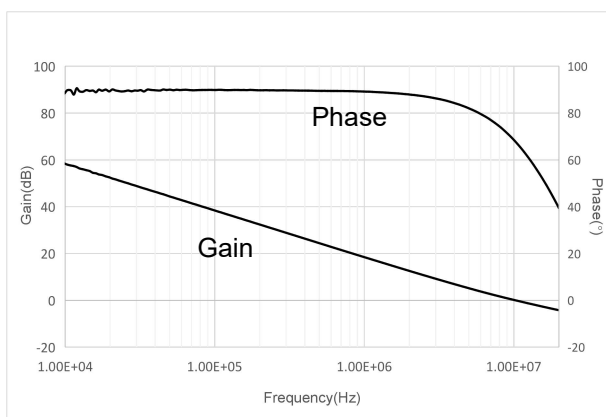
Offset Voltage vs Common-Mode Voltage



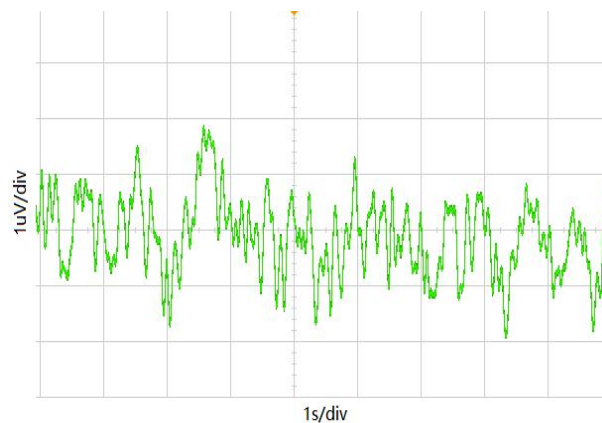
Quiescent Current vs Temperature



Quiescent Current vs Supply Voltage



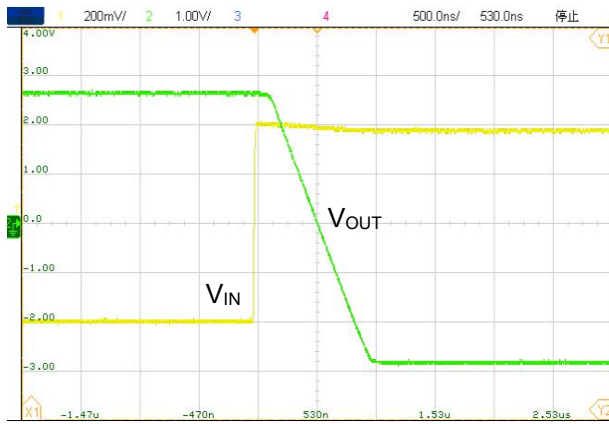
Open-Loop Gain vs Frequency



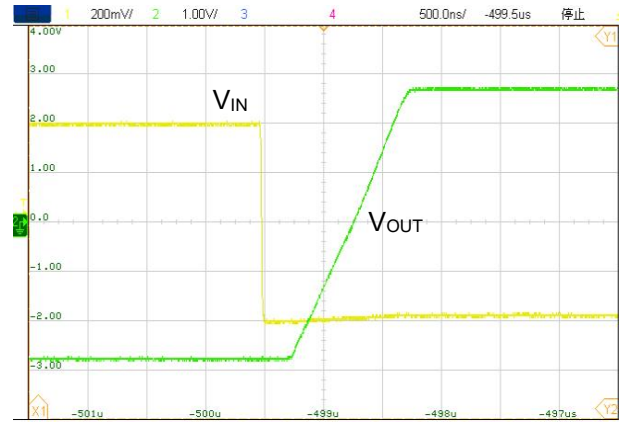
0.1 Hz to 10 Hz Noise

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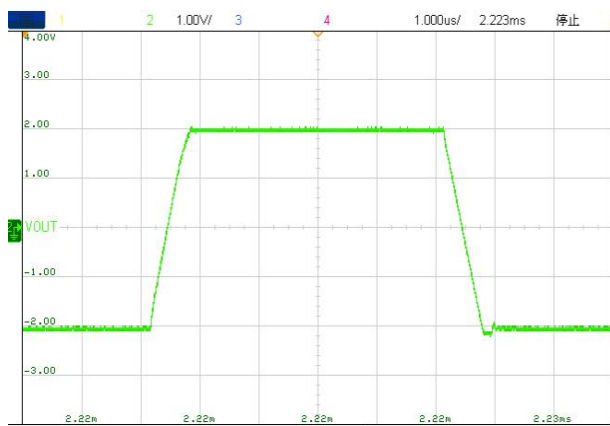
Typical Characteristics (Continued)



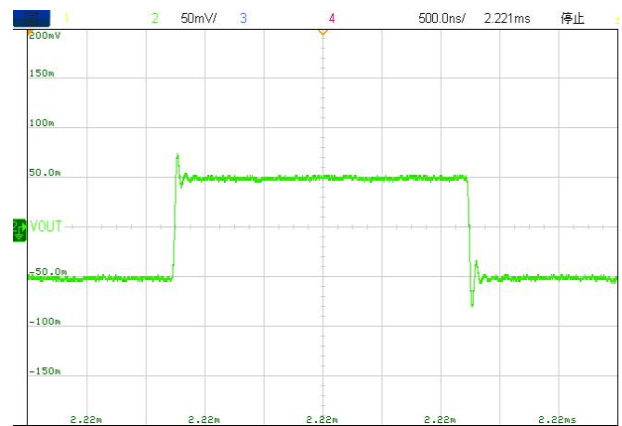
Positive Overload Recovery
($G = -10$)



Negative Overload Recovery
($G = -10$)



Large-Signal Step Response
($G = +1$)



Small-Signal Step Response(100 mV)
($G = +1, R_L = 10 \text{ k}\Omega, C_L = 100 \text{ pF}$)

Application Notes

Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

Place the external components as close to the device as possible. This configuration prevents parasitic errors (such as the Seebeck effect) from occurring.

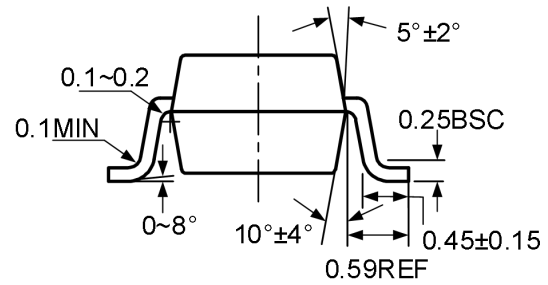
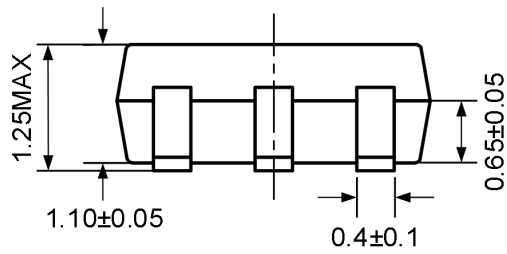
To reduce parasitic coupling, run the input traces as far away from the supply lines and digital signal as possible. Low-ESR, 0.1 μ F ceramic bypass capacitors must be connected between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable to single supply applications.

Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.

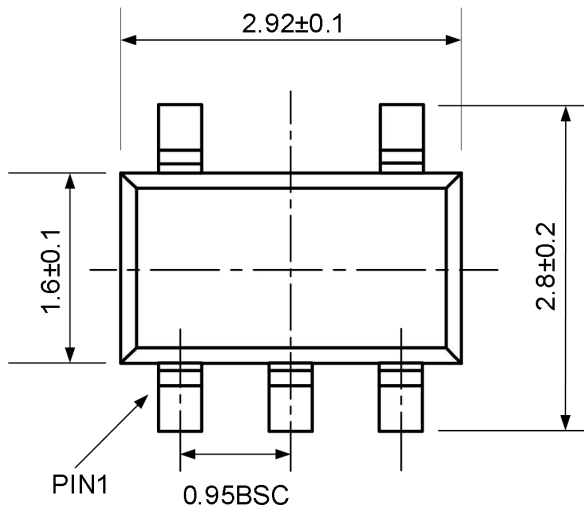
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Package Dimension

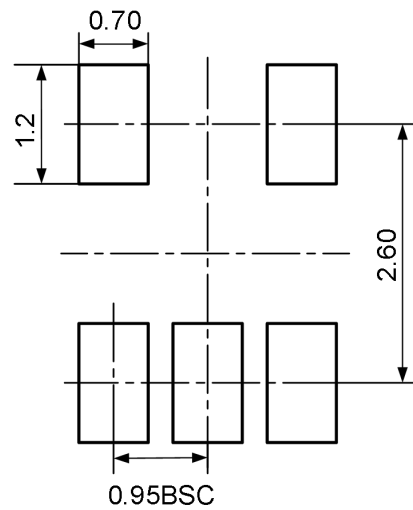
SOT23-5



SIDE VIEW



TOP VIEW

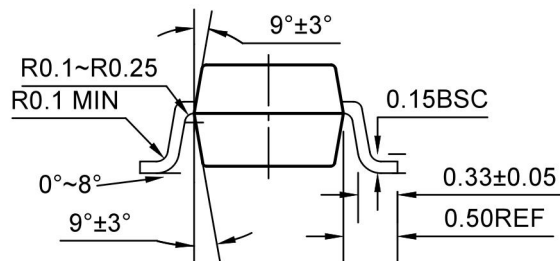
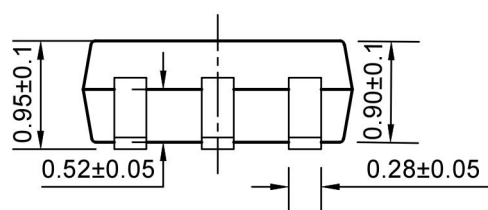


Recommended Land Pattern

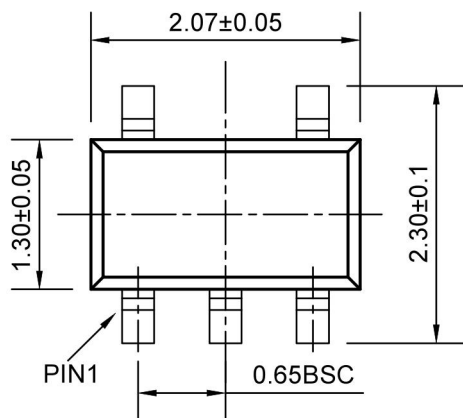
Unit: mm

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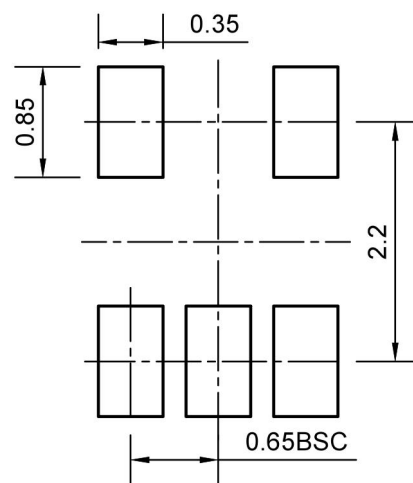
SC70-5



SIDE VIEW



TOP VIEW



Recommended Land Pattern

Unit: mm

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Revision History and Checking Table

Version	Date	Revision Item	Modifier	Function & Spec Checking	Package & Tape Checking
0.0	2023-04-21	Preliminary Version	Huyt	Wanggp	Liujiy
1.0	2023-08-31	Original Version	Huyt	Chenh	Liujiy
1.1	2023-9-27	Naming updates	Shibo	Wanggp	Liujiy
1.2	2025-4-11	Update MSL Grade	Huyt	Chenh	Liujiy
1.3	2025-4-17	Update Typical Characteristics	Huyt	Tangyx	Liujiy